1 Characteristics

Table 2: Absolute maximum ratings (limiting values), T_j = 25 °C unless otherwise specified

Symbol	Parameter			Value	Unit
$I_{T(RMS)}$	RMS on-state current (180 ° conduction angle)		T_c = 76 °C	12	A
$I_{T(AV)}$	Average on-state current (180 ° conduction angle)		T_c = 73 °C	8	A
I_{TSM}	Non repetitive surge peak on-state current (T_j initial = 25 °C)		t_p = 8.3 ms	120	A
			t_p = 10 ms	110	
I^2t	I^2t value for fusing		t_p = 10 ms	60.5	A^2s
dI/dt	Critical rate of rise of on-state current I_G = 2 x I_{GT}, tr ≤ 100 ns		f = 60 Hz	100	A/µs
V_{DRM}/V_{RRM}	Repetitive peak off-state voltage		T_j = 125 °C	600	V
I_{GM}	Peak gate current	t_p = 20 µs	T_j = 125 °C	4	A
$P_{G(AV)}$	Average gate power dissipation		T_j = 125 °C	1	W
V_{RGM}	Maximum peak reverse gate voltage			5	V
T_{stg}	Storage junction temperature range			-40 to +150	°C
T_j	Operating junction temperature range			-40 to +125	°C
T_L	Maximum lead temperature for soldering during 10 s			260	°C
$V_{INS(RMS)}$	Insulation RMS voltage, 60 seconds			2000	V

Table 3: Electrical characteristics (T_j = 25 °C unless otherwise specified)

Symbol	Test conditions			Value	Unit
I_{GT}	V_D = 12 V, R_L = 140 Ω		Max.	200	µA
V_{GT}			Max.	0.8	V
V_{GD}	V_D = V_{DRM}, R_L = 3.3 kΩ, R_{GK} = 220 Ω	T_j = 125 °C	Min.	0.1	V
V_{RG}	I_{RG} = 10 µA		Min.	8	V
I_H	I_T = 50 mA, R_{GK} = 1 KΩ		Max.	5	mA
I_L	I_G = 1 mA, R_{GK} = 1 KΩ		Max.	6	mA
dV/dt	V_D = 402 V, R_{GK} = 220 Ω	T_j = 125 °C	Min.	5	V/µs
t_{gt}	I_{TM} = 24 A, V_D = 402 V, I_G = 10 mA, (dI_G/dt) max = 0.2 A/µs		Typ.	1.9	µs
t_q	I_{TM} = 12 A, V_D = 402 V, (d_I/dt)off = 10 A/µs, V_R = 25 V, dV_D/dt = 1 V/µs, R_{GK} = 220 Ω	T_j = 110 °C	Typ.	200	µs

Table 4: Static characteristics

Symbol	Test conditions			Value	Unit
V_{TM}	I_{TM} = 24 A, t_p = 380 µs	T_j = 25 °C	Max.	1.6	V
V_{TO}	Threshold voltage	T_j = 125 °C	Max.	0.85	
R_D	Dynamic resistance	T_j = 125 °C	Max.	30	mΩ
I_{DRM}, I_{RRM}	$V_D = V_{DRM}$, $V_R = V_{RRM}$, R_{GK} = 220 Ω	T_j = 25 °C	Max.	5	µA
		T_j = 125 °C		2	mA

Table 5: Thermal parameters

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction to case (DC)	Max.	4.5	°C/W
$R_{th(j-a)}$	Junction to ambient (DC)	Typ.	60	

1.1 Characteristics (curves)

Figure 1: Maximum average power dissipation versus average on-state current

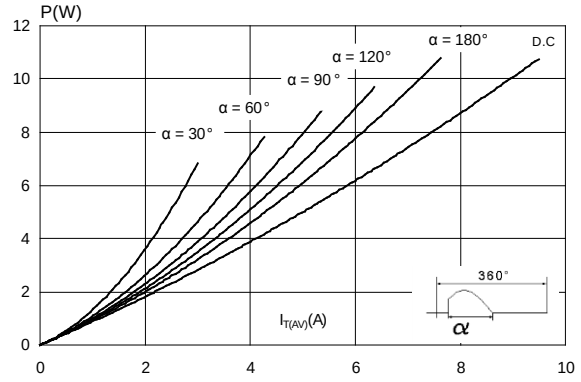


Figure 2: Average and DC on-state current versus case temperature

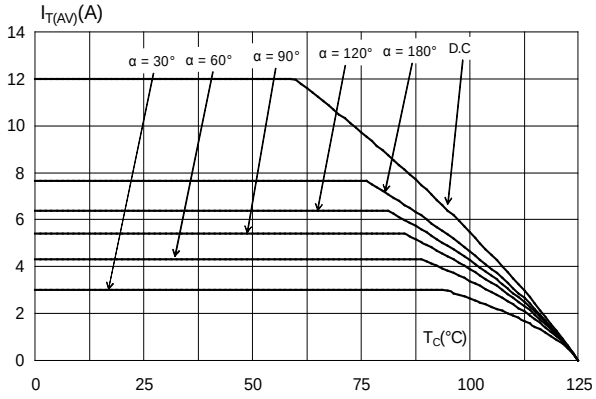


Figure 3: Average and D.C. on state current versus ambient temperature

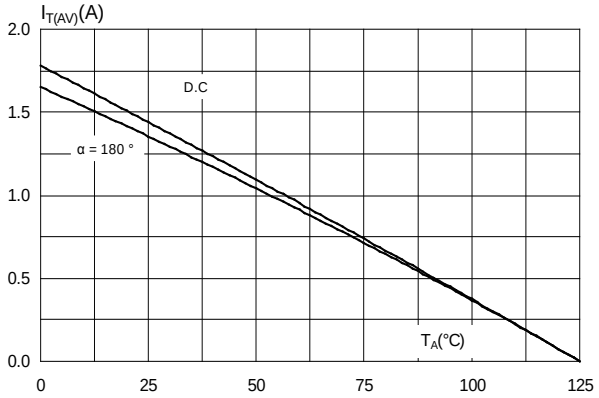


Figure 4: Relative variation of thermal impedance junction to case and junction to ambient versus pulse duration

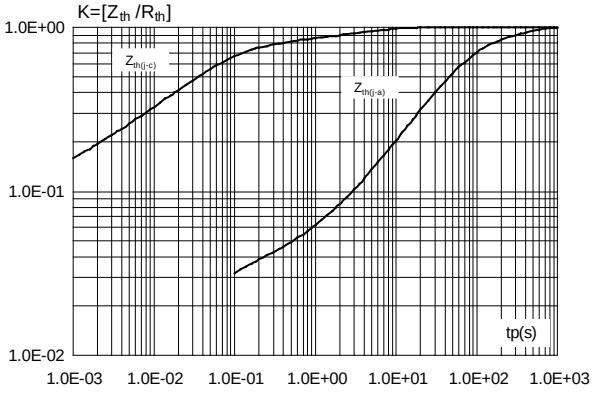


Figure 5: Relative variation of gate trigger and holding current versus junction temperature

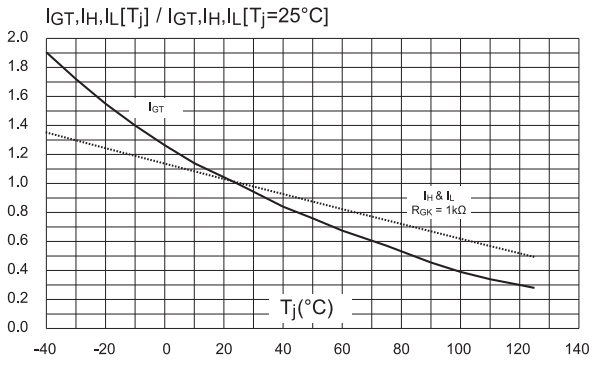


Figure 6: Relative variation of holding current versus gate-cathode resistance (typical values)

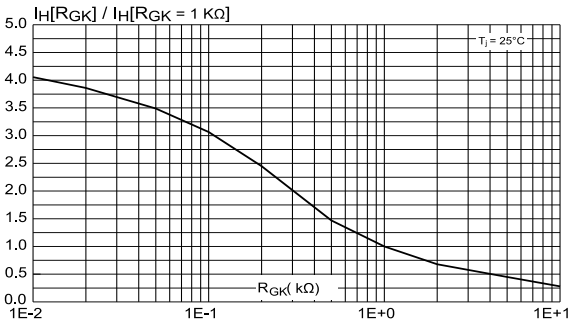


Figure 7: Relative variation of dV/dt immunity versus gate-cathode resistance (typical values)

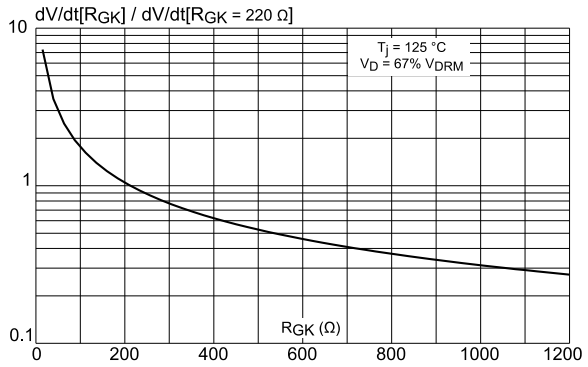


Figure 8: Relative variation of dV/dt immunity current versus gate-cathode capacitance (typical values)

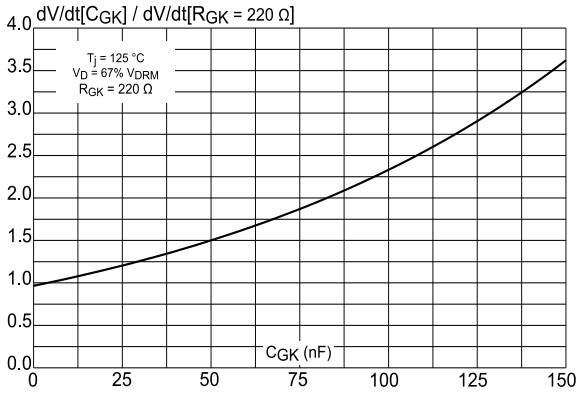


Figure 9: Surge peak on-state current versus number of cycles

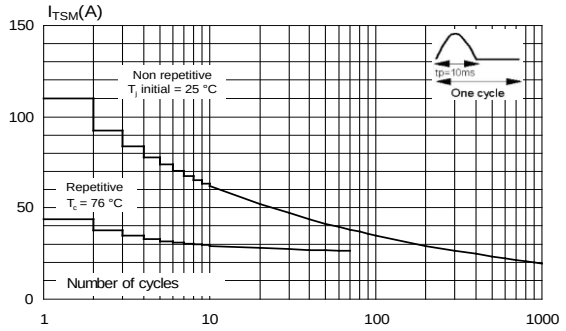


Figure 10: Non repetitive surge peak on-state current for a sinusoidal pulse with width t_p < 10 ms

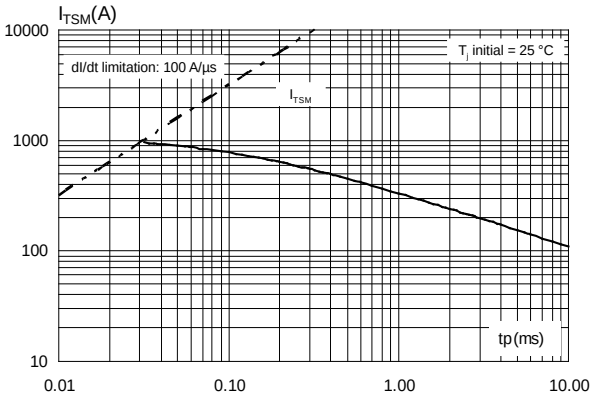
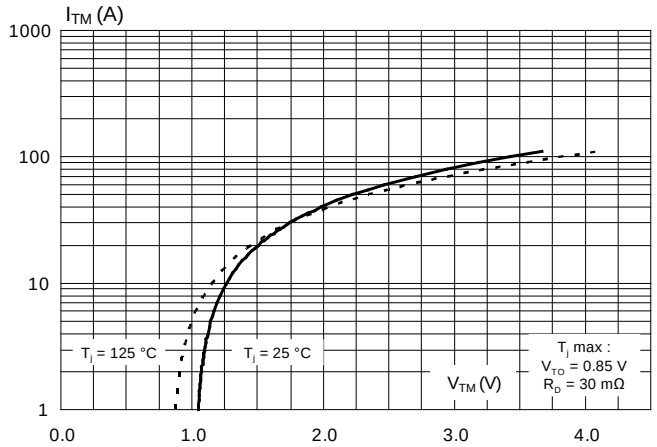


Figure 11: On-state characteristics (maximum values)



2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: ***www.st.com***. ECOPACK® is an ST trademark.

- Epoxy meets UL94, V0
- Lead-free, halogen-free package
- Recommended torque value (TO-220FPAB): 0.4 to 0.6 N.m

2.1 TO-220AB package information

Figure 12: TO-220FPAB package outline

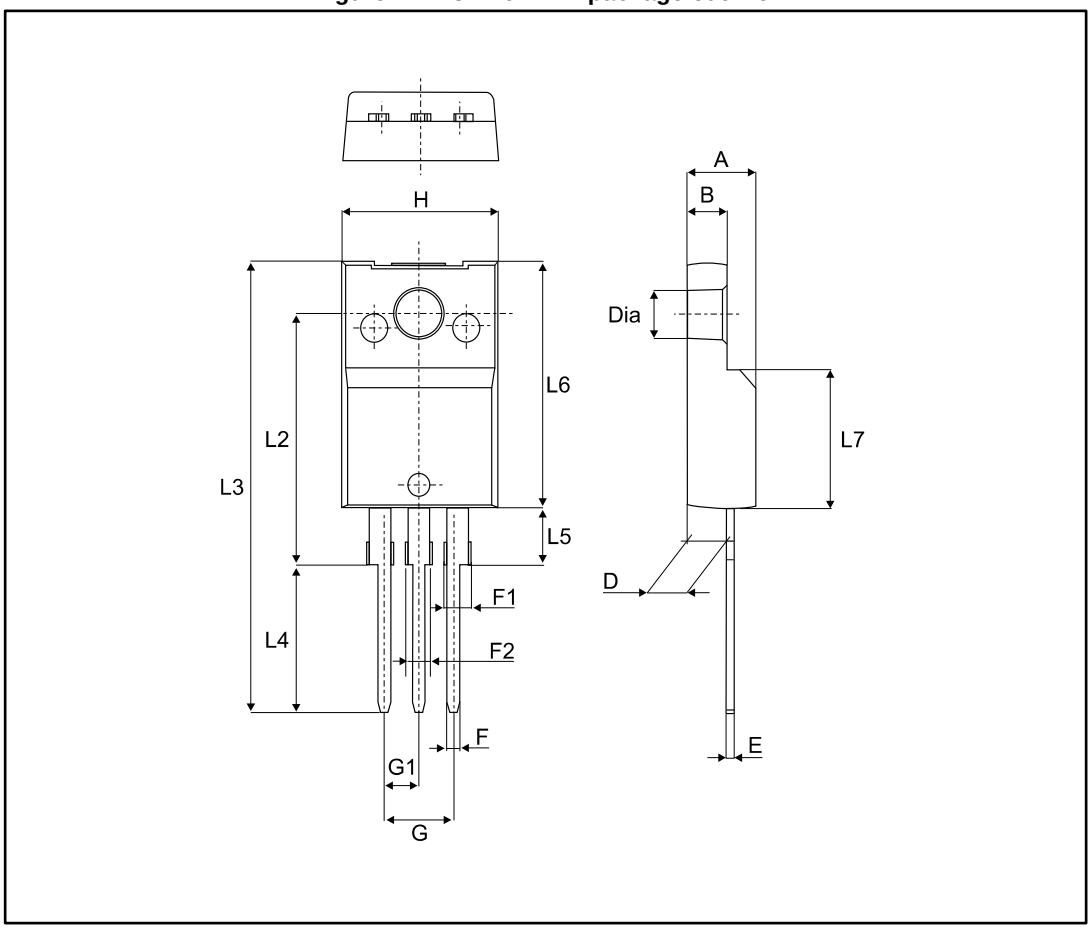


Table 6: TO-220FPAB package mechanical data

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.1739	0.1818
B	2.5	2.7	0.0988	0.1067
D	2.50	2.75	0.0988	0.1087
E	0.45	0.70	0.0178	0.0277
F	0.75	1.0	0.0296	0.0395
F1	1.15	1.70	0.0455	0.0672
F2	1.15	1.70	0.0455	0.0672
G	4.95	5.20	0.1957	0.2055
G1	2.40	2.70	0.0949	0.1067
H	10.00	10.40	0.3953	0.4111
L2	16.00 typ.		0.6324 typ.	
L3	28.60	30.60	1.1304	1.2095
L4	9.80	10.6	0.3874	0.4190
L5	2.90	3.60	0.1146	0.1423
L6	15.90	16.40	0.6285	0.6482
L7	9.00	9.30	0.3557	0.3676
Dia	3.0	3.20	0.1186	0.1265

3 Ordering information

Figure 13: Ordering information scheme

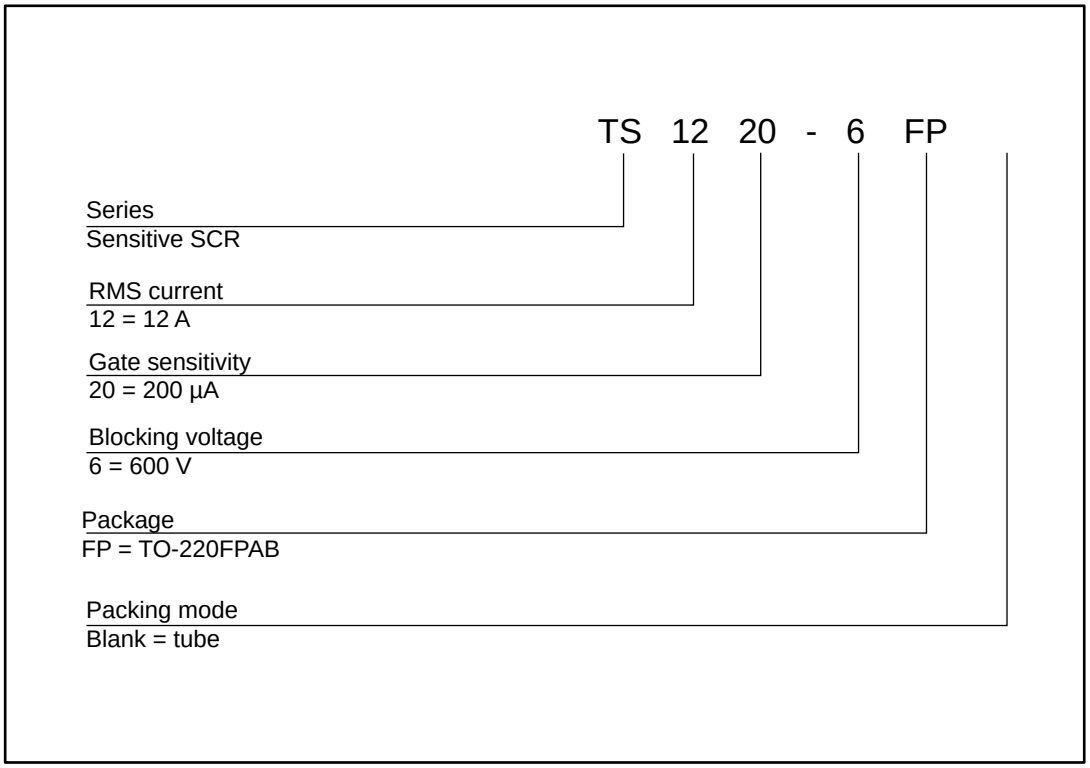


Table 7: Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
TS1220-6FP	TS1220-6	TO-220FPAB	2.0 g	50	Tube

4 Revision history

Table 8: Document revision history

Date	Revision	Changes
31-Aug-2017	1	Initial release.

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